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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	M8C
Core Size	8-Bit
Speed	24MHz
Connectivity	I ² C, SPI, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	24
Program Memory Size	4KB (4K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	256 x 8
Voltage - Supply (Vcc/Vdd)	2.4V ~ 5.25V
Data Converters	A/D 10x14b; D/A 2x9b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	28-SSOP (0.209", 5.30mm Width)
Supplier Device Package	28-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy8c24423a4-24pvxi

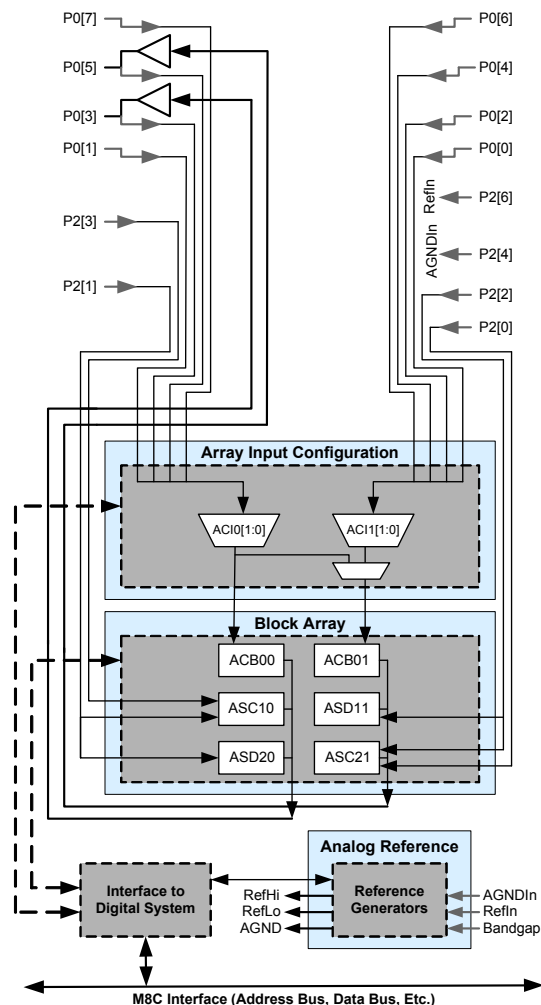
Analog System

The analog system consists of six configurable blocks, each consisting of an opamp circuit that allows the creation of complex analog signal flows. Analog peripherals are very flexible and can be customized to support specific application requirements. Some of the more common PSoC analog functions (most available as user modules) are:

- ADCs (up to two, with 6- to 14-bit resolution, selectable as incremental, delta sigma, and SAR)
- Filters (two and four pole band-pass, low-pass, and notch)
- Amplifiers (up to two, with selectable gain to 48x)
- Instrumentation amplifiers (one with selectable gain to 93x)
- Comparators (up to two, with 16 selectable thresholds)
- DACs (up to two, with 6 to 9-bit resolution)
- Multiplying DACs (up to two, with 6 to 9-bit resolution)
- High current output drivers (two with 30 mA drive as a PSoC Core resource)
- 1.3 V reference (as a system resource)
- DTMF dialer
- Modulators
- Correlators
- Peak detectors
- Many other topologies possible

Analog blocks are arranged in a column of three, which includes one continuous time (CT) and two switched capacitor (SC) blocks, as shown in [Figure 3](#)

Figure 3. Analog System Block Diagram



Additional System Resources

System resources, some of which are listed in the previous sections, provide additional capability useful to complete systems. Additional resources include a multiplier, decimator, switch-mode pump, low-voltage detection, and power-on-reset (POR). Statements describing the merits of each system resource follow:

- Digital clock dividers provide three customizable clock frequencies for use in applications. The clocks can be routed to both the digital and analog systems. Additional clocks may be generated using digital PSoC blocks as clock dividers.
- A multiply accumulate (MAC) provides a fast 8-bit multiplier with 32-bit accumulate, to assist in both general math and digital filters.

- The decimator provides a custom hardware filter for digital signal processing applications including the creation of Delta Sigma ADCs.
- The I²C module provides 100- and 400-kHz communication over two wires. slave, master, and multi-master are supported.
- Low-voltage detection (LVD) interrupts can signal the application of falling voltage levels, while the advanced POR circuit eliminates the need for a system supervisor.
- An internal 1.3 V reference provides an absolute reference for the analog system, including ADCs and DACs.
- An integrated switch-mode pump generates normal operating voltages from a single 1.2 V battery cell, providing a low cost boost converter.

PSoC Device Characteristics

Depending on your PSoC device characteristics, the digital and analog systems can have 16, 8, or 4 digital blocks, and 12, 6, or 4 analog blocks. [Table 1 on page 6](#) lists the resources available for specific PSoC device groups. The PSoC device covered by this datasheet is highlighted in this table.

Table 1. PSoC Device Characteristics

PSoC Part Number	Digital I/O	Digital Rows	Digital Blocks	Analog Inputs	Analog Outputs	Analog Columns	Analog Blocks	SRAM Size	Flash Size
CY8C29x66	up to 64	4	16	up to 12	4	4	12	2 K	32 K
CY8C28xxx	up to 44	up to 3	up to 12	up to 44	up to 4	up to 6	up to 12 + 4 ^[2]	1 K	16 K
CY8C27x43	up to 44	2	8	up to 12	4	4	12	256	16 K
CY8C24x94	up to 56	1	4	up to 48	2	2	6	1 K	16 K
CY8C24x23A	up to 24	1	4	up to 12	2	2	6	256	4 K
CY8C23x33	up to 26	1	4	up to 12	2	2	4	256	8 K
CY8C22x45	up to 38	2	8	up to 38	0	4	6 ^[2]	1 K	16 K
CY8C21x45	up to 24	1	4	up to 24	0	4	6 ^[2]	512	8 K
CY8C21x34	up to 28	1	4	up to 28	0	2	4 ^[2]	512	8 K
CY8C21x23	up to 16	1	4	up to 8	0	2	4 ^[2]	256	4 K
CY8C20x34	up to 28	0	0	up to 28	0	0	3 ^[2,3]	512	8 K
CY8C20xx6	up to 36	0	0	up to 36	0	0	3 ^[2,3]	up to 2 K	up to 32 K

Notes

2. Limited analog functionality.
3. Two analog blocks and one CapSense®.

Development Tools

PSoC Designer™ is the revolutionary integrated design environment (IDE) that you can use to customize PSoC to meet your specific application requirements. PSoC Designer software accelerates system design and time to market. Develop your applications using a library of precharacterized analog and digital peripherals (called user modules) in a drag-and-drop design environment. Then, customize your design by leveraging the dynamically generated application programming interface (API) libraries of code. Finally, debug and test your designs with the integrated debug environment, including in-circuit emulation and standard software debug features. PSoC Designer includes:

- Application editor graphical user interface (GUI) for device and user module configuration and dynamic reconfiguration
- Extensive user module catalog
- Integrated source-code editor (C and assembly)
- Free C compiler with no size restrictions or time limits
- Built-in debugger
- In-circuit emulation
- Built-in support for communication interfaces:
 - Hardware and software I²C slaves and masters
 - Full-speed USB 2.0
 - Up to four full-duplex universal asynchronous receiver/transmitters (UARTs), SPI master and slave, and wireless

PSoC Designer supports the entire library of PSoC 1 devices and runs on Windows XP, Windows Vista, and Windows 7.

PSoC Designer Software Subsystems

Design Entry

In the chip-level view, choose a base device to work with. Then select different onboard analog and digital components that use the PSoC blocks, which are called user modules. Examples of user modules are analog-to-digital converters (ADCs), digital-to-analog converters (DACs), amplifiers, and filters. Configure the user modules for your chosen application and connect them to each other and to the proper pins. Then generate your project. This prepopulates your project with APIs and libraries that you can use to program your application.

The tool also supports easy development of multiple configurations and dynamic reconfiguration. Dynamic reconfiguration makes it possible to change configurations at run time. In essence, this lets you to use more than 100 percent of PSoC's resources for an application.

Code Generation Tools

The code generation tools work seamlessly within the PSoC Designer interface and have been tested with a full range of debugging tools. You can develop your design in C, assembly, or a combination of the two.

Assemblers. The assemblers allow you to merge assembly code seamlessly with C code. Link libraries automatically use absolute addressing or are compiled in relative mode, and linked with other software modules to get absolute addressing.

C Language Compilers. C language compilers are available that support the PSoC family of devices. The products allow you to create complete C programs for the PSoC family devices. The optimizing C compilers provide all of the features of C, tailored to the PSoC architecture. They come complete with embedded libraries providing port and bus operations, standard keypad and display support, and extended math functionality.

Debugger

PSoC Designer has a debug environment that provides hardware in-circuit emulation, allowing you to test the program in a physical system while providing an internal view of the PSoC device. Debugger commands allow you to read and program and read and write data memory, and read and write I/O registers. You can read and write CPU registers, set and clear breakpoints, and provide program run, halt, and step control. The debugger also lets you to create a trace buffer of registers and memory locations of interest.

Online Help System

The online help system displays online, context-sensitive help. Designed for procedural and quick reference, each functional subsystem has its own context-sensitive help. This system also provides tutorials and links to FAQs and an Online Support Forum to aid the designer.

In-Circuit Emulator

A low-cost, high-functionality in-circuit emulator (ICE) is available for development support. This hardware can program single devices.

The emulator consists of a base unit that connects to the PC using a USB port. The base unit is universal and operates with all PSoC devices. Emulation pods for each device family are available separately. The emulation pod takes the place of the PSoC device in the target board and performs full-speed (24 MHz) operation.

Designing with PSoC Designer

The development process for the PSoC device differs from that of a traditional fixed-function microprocessor. The configurable analog and digital hardware blocks give the PSoC architecture a unique flexibility that pays dividends in managing specification change during development and lowering inventory costs. These configurable resources, called PSoC blocks, have the ability to implement a wide variety of user-selectable functions. The PSoC development process is:

6. Select [user modules](#).
7. Configure user modules.
8. Organize and connect.
9. Generate, verify, and debug.

Select User Modules

PSoC Designer provides a library of prebuilt, pretested hardware peripheral components called “user modules.” User modules make selecting and implementing peripheral devices, both analog and digital, simple.

Configure User Modules

Each user module that you select establishes the basic register settings that implement the selected function. They also provide parameters and properties that allow you to tailor their precise configuration to your particular application. For example, a PWM User Module configures one or more digital PSoC blocks, one for each eight bits of resolution. Using these parameters, you can establish the pulse width and duty cycle. Configure the parameters and properties to correspond to your chosen application. Enter values directly or by selecting values from drop-down menus. All of the user modules are documented in datasheets that may be viewed directly in PSoC Designer or on the Cypress website. These [user module datasheets](#) explain the internal operation of the user module and provide performance specifications. Each datasheet describes the use of each user

module parameter, and other information that you may need to successfully implement your design.

Organize and Connect

Build signal chains at the chip level by interconnecting user modules to each other and the I/O pins. Perform the selection, configuration, and routing so that you have complete control over all on-chip resources.

Generate, Verify, and Debug

When you are ready to test the hardware configuration or move on to developing code for the project, perform the “Generate Configuration Files” step. This causes PSoC Designer to generate source code that automatically configures the device to your specification and provides the software for the system. The generated code provides APIs with high-level functions to control and respond to hardware events at run time, and interrupt service routines that you can adapt as needed.

A complete code development environment lets you to develop and customize your applications in C, assembly language, or both.

The last step in the development process takes place inside PSoC Designer's Debugger (accessed by clicking the Connect icon). PSoC Designer downloads the HEX image to the ICE where it runs at full-speed. PSoC Designer debugging capabilities rival those of systems costing many times more. In addition to traditional single-step, run-to-breakpoint, and watch-variable features, the debug interface provides a large trace buffer. It lets you to define complex breakpoint events that include monitoring address and data bus values, memory locations, and external signals.

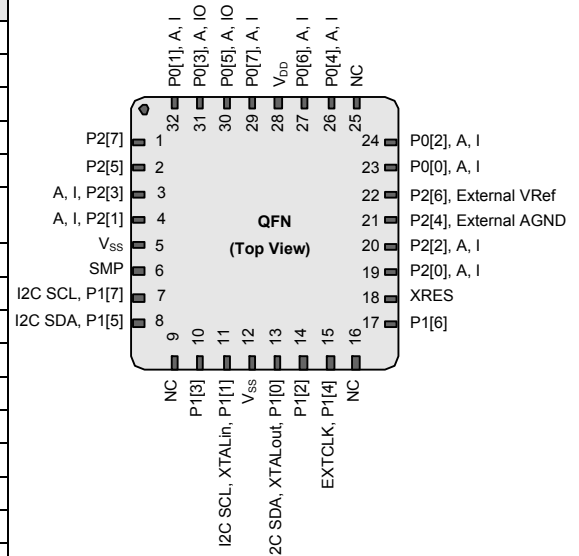
32-Pin Part Pinout

Table 5. 32-Pin QFN^[7]

Pin No.	Type		Pin Name	Description
	Digital	Analog		
1	I/O		P2[7]	
2	I/O		P2[5]	
3	I/O	I	P2[3]	Direct switched capacitor block input
4	I/O	I	P2[1]	Direct switched capacitor block input
5	Power		V _{SS}	Ground connection
6	Power		SMP	SMP connection to external components required
7	I/O		P1[7]	I ² C SCL
8	I/O		P1[5]	I ² C SDA
9			NC	No connection. Pin must be left floating
10	I/O		P1[3]	
11	I/O		P1[1]	XTALin, I ² C SCL, ISSP-SCLK ^[8]
12	Power		V _{SS}	Ground Connection
13	I/O		P1[0]	XTALout, I ² C SDA, ISSP-SDATA ^[8]
14	I/O		P1[2]	
15	I/O		P1[4]	Optional EXTCLK
16			NC	No connection. Pin must be left floating
17	I/O		P1[6]	
18	Input		XRES	Active high external reset with internal pull-down
19	I/O	I	P2[0]	Direct switched capacitor block input
20	I/O	I	P2[2]	Direct switched capacitor block input
21	I/O		P2[4]	External AGND
22	I/O		P2[6]	External V _{REF}
23	I/O	I	P0[0]	Analog column mux input
24	I/O	I	P0[2]	Analog column mux input
25			NC	No connection. Pin must be left floating
26	I/O	I	P0[4]	Analog column mux input
27	I/O	I	P0[6]	Analog column mux input
28	Power		V _{DD}	Supply voltage
29	I/O	I	P0[7]	Analog column mux input
30	I/O	I/O	P0[5]	Analog column mux input and column output
31	I/O	I/O	P0[3]	Analog column mux input and column output
32	I/O	I	P0[1]	Analog column mux input

LEGEND: A = Analog, I = Input, and O = Output.

Figure 7. CY8C24423A 32-Pin PSoC Device



Notes

- The center pad on the QFN package must be connected to ground (V_{SS}) for best mechanical, thermal, and electrical performance. If not connected to ground, it must be electrically floated and not connected to any other signal.
- These are the ISSP pins, which are not high Z at POR. See the [PSoC Technical Reference Manual](#) for details.

Electrical Specifications

This section presents the DC and AC electrical specifications of the CY8C24x23A PSoC device. For the latest electrical specifications, check if you have the most recent datasheet by visiting the website at <http://www.cypress.com>.

Specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$ and $T_J \leq 100^{\circ}\text{C}$, except where noted.

Refer to [Table 29 on page 37](#) for the electrical specifications for the IMO using SLIMO mode.

Figure 9. Voltage versus CPU Frequency

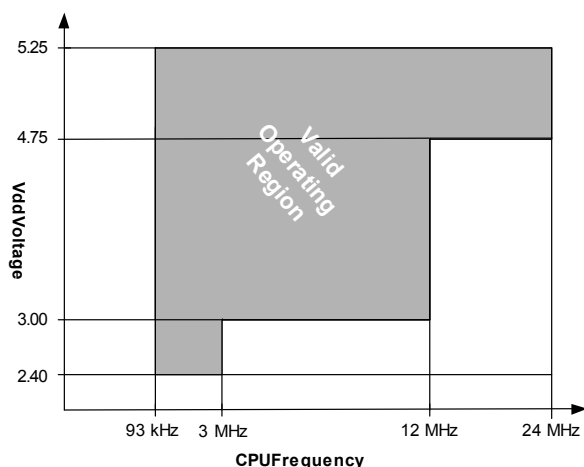
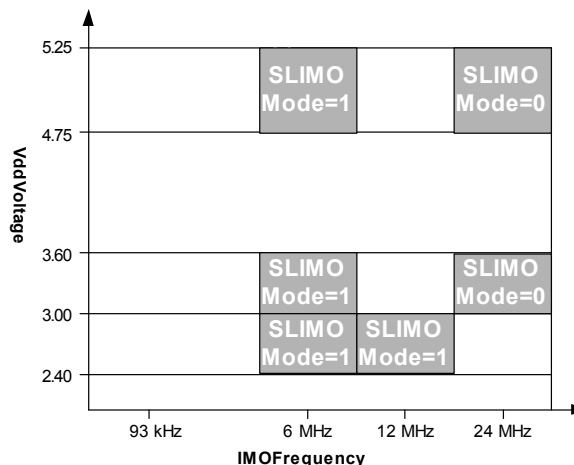


Figure 8. IMO Frequency Trim Options



Absolute Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. User guidelines are not tested.

Table 9. Absolute Maximum Ratings

Symbol	Description	Min	Typ	Max	Units	Notes
T_{STG}	Storage temperature	-55	25	+100	$^{\circ}\text{C}$	Higher storage temperatures reduce data retention time. Recommended storage temperature is $+25^{\circ}\text{C} \pm 25^{\circ}\text{C}$. Extended duration storage temperatures above 65°C degrades reliability.
$T_{BAKETEMP}$	Bake temperature	—	125	See package label	$^{\circ}\text{C}$	
$t_{BAKETIME}$	Bake time	See package label	—	72	Hours	
T_A	Ambient temperature with power applied	-40	—	+85	$^{\circ}\text{C}$	
V_{DD}	Supply voltage on V_{DD} relative to V_{SS}	-0.5	—	+6.0	V	
V_{IO}	DC input voltage	$V_{SS} - 0.5$	—	$V_{DD} + 0.5$	V	
V_{IOZ}	DC voltage applied to tri-state	$V_{SS} - 0.5$	—	$V_{DD} + 0.5$	V	
I_{MIO}	Maximum current into any port pin	-25	—	+50	mA	
ESD	Electrostatic discharge voltage	2000	—	—	V	Human body model ESD.
LU	Latch up current	—	—	200	mA	

DC Analog Output Buffer Specifications

The following tables list the guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 2.4 V to 3.0 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters are measured at 5 V, 3.3 V, and 2.7 V at 25°C and are for design guidance only.

Table 18. 5-V DC Analog Output Buffer Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
C_L	Load Capacitance	–	–	200	pF	This specification applies to the external circuit that is being driven by the analog output buffer.
V_{OSOB}	Input offset voltage (absolute value)	–	3	12	mV	
TCV_{OSOB}	Average input offset voltage drift	–	+6	–	$\mu\text{V}/^{\circ}\text{C}$	
V_{CMOB}	Common mode input voltage range	0.5	–	$V_{DD} - 1.0$	V	
R_{OUTOB}	Output resistance Power = low Power = high	– –	1 1	– –	W W	
$V_{OHIGHOB}$	High output voltage swing (Load = 32 ohms to $V_{DD/2}$) Power = low Power = high	$0.5 \times V_{DD} + 1.1$ $0.5 \times V_{DD} + 1.1$	– –	– –	V V	
V_{OLOWOB}	Low output voltage swing (Load = 32 ohms to $V_{DD/2}$) Power = low Power = high	– –	– –	$.5 \times V_{DD} - 1.3$ $0.5 \times V_{DD} - 1.3$	V V	
I_{SOB}	Supply current including Opamp bias cell (No Load) Power = low Power = high	– –	1.1 2.6	5.1 8.8	mA mA	
$PSRR_{OB}$	Supply voltage rejection ratio	52	64	–	dB	$V_{OUT} > (V_{DD} - 1.25)$

Table 19. 3.3-V DC Analog Output Buffer Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
C_L	Load Capacitance	–	–	200	pF	This specification applies to the external circuit that is being driven by the analog output buffer.
V_{OSOB}	Input offset voltage (absolute value)	–	3	12	mV	
TCV_{OSOB}	Average input offset voltage drift	–	+6	–	$\mu\text{V}/^{\circ}\text{C}$	
V_{CMOB}	Common mode input voltage range	0.5	–	$V_{DD} - 1.0$	V	
R_{OUTOB}	Output resistance Power = low Power = high	– –	1 1	– –	Ω Ω	
$V_{OHIGHOB}$	High output voltage swing (Load = 1 K ohms to $V_{DD/2}$) Power = low Power = high	$0.5 \times V_{DD} + 1.0$ $0.5 \times V_{DD} + 1.0$	– –	– –	V V	
V_{OLOWOB}	Low output voltage swing (Load = 1 K ohms to $V_{DD/2}$) Power = low Power = high	– –	– –	$0.5 \times V_{DD} - 1.0$ $0.5 \times V_{DD} - 1.0$	V V	
I_{SOB}	Supply current including Opamp bias cell (no load) Power = low Power = high	– –	0.8 2.0	2.0 4.3	mA mA	
$PSRR_{OB}$	Supply voltage rejection ratio	52	64	–	dB	$V_{OUT} > (V_{DD} - 1.25)$

Table 22. 5-V DC Analog Reference Specifications (continued)

Reference ARE_CR [5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Units
0b010	RefPower = high Opamp bias = high	V _{REFHI}	Ref High	V _{DD}	V _{DD} – 0.121	V _{DD} – 0.003	V _{DD}	V
		V _{AGND}	AGND	V _{DD} /2	V _{DD} /2 – 0.040	V _{DD} /2	V _{DD} /2 + 0.034	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.006	V _{SS} + 0.019	V
	RefPower = high Opamp bias = low	V _{REFHI}	Ref High	V _{DD}	V _{DD} – 0.083	V _{DD} – 0.002	V _{DD}	V
		V _{AGND}	AGND	V _{DD} /2	V _{DD} /2 – 0.040	V _{DD} /2 – 0.001	V _{DD} /2 + 0.033	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.004	V _{SS} + 0.016	V
	RefPower = medium Opamp bias = high	V _{REFHI}	Ref High	V _{DD}	V _{DD} – 0.075	V _{DD} – 0.002	V _{DD}	V
		V _{AGND}	AGND	V _{DD} /2	V _{DD} /2 – 0.040	V _{DD} /2 – 0.001	V _{DD} /2 + 0.032	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.003	V _{SS} + 0.015	V
	RefPower = medium Opamp bias = low	V _{REFHI}	Ref High	V _{DD}	V _{DD} – 0.074	V _{DD} – 0.002	V _{DD}	V
		V _{AGND}	AGND	V _{DD} /2	V _{DD} /2 – 0.040	V _{DD} /2 – 0.001	V _{DD} /2 + 0.032	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.002	V _{SS} + 0.014	V
0b011	RefPower = high Opamp bias = high	V _{REFHI}	Ref High	3 × Bandgap	3.753	3.874	3.979	V
		V _{AGND}	AGND	2 × Bandgap	2.511	2.590	2.657	V
		V _{REFLO}	Ref Low	Bandgap	1.243	1.297	1.333	V
	RefPower = high Opamp bias = low	V _{REFHI}	Ref High	3 × Bandgap	3.767	3.881	3.974	V
		V _{AGND}	AGND	2 × Bandgap	2.518	2.592	2.652	V
		V _{REFLO}	Ref Low	Bandgap	1.241	1.295	1.330	V
	RefPower = medium Opamp bias = high	V _{REFHI}	Ref High	3 × Bandgap	2.771	3.885	3.979	V
		V _{AGND}	AGND	2 × Bandgap	2.521	2.593	2.649	V
		V _{REFLO}	Ref Low	Bandgap	1.240	1.295	1.331	V
	RefPower = medium Opamp bias = low	V _{REFHI}	Ref High	3 × Bandgap	3.771	3.887	3.977	V
		V _{AGND}	AGND	2 × Bandgap	2.522	2.594	2.648	V
		V _{REFLO}	Ref Low	Bandgap	1.239	1.295	1.332	V
0b100	RefPower = high Opamp bias = high	V _{REFHI}	Ref High	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.481 + P2[6]	2.569 + P2[6]	2.639 + P2[6]	V
		V _{AGND}	AGND	2 × Bandgap	2.511	2.590	2.658	V
		V _{REFLO}	Ref Low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.515 – P2[6]	2.602 – P2[6]	2.654 – P2[6]	V
	RefPower = high Opamp bias = low	V _{REFHI}	Ref High	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.498 + P2[6]	2.579 + P2[6]	2.642 + P2[6]	V
		V _{AGND}	AGND	2 × Bandgap	2.518	2.592	2.652	V
		V _{REFLO}	Ref Low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.513 – P2[6]	2.598 – P2[6]	2.650 – P2[6]	V
	RefPower = medium Opamp bias = high	V _{REFHI}	Ref High	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.504 + P2[6]	2.583 + P2[6]	2.646 + P2[6]	V
		V _{AGND}	AGND	2 × Bandgap	2.521	2.592	2.650	V
		V _{REFLO}	Ref Low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.513 – P2[6]	2.596 – P2[6]	2.649 – P2[6]	V
	RefPower = medium Opamp bias = low	V _{REFHI}	Ref High	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.505 + P2[6]	2.586 + P2[6]	2.648 + P2[6]	V
		V _{AGND}	AGND	2 × Bandgap	2.521	2.594	2.648	V
		V _{REFLO}	Ref Low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.513 – P2[6]	2.595 – P2[6]	2.648 – P2[6]	V

Table 24. 2.7-V DC Analog Reference Specifications

Reference ARF_CR [5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Units
0b000	All power settings Not allowed at 2.7 V	—	—	—	—	—	—	—
0b001	RefPower = medium Opamp bias = high	V _{REFHI}	Ref High	P2[4]+P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V)	P2[4] + P2[6] – 0.739	P2[4] + P2[6] – 0.016	P2[4] + P2[6] + 0.759	V
		V _{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	—
		V _{REFLO}	Ref Low	P2[4]–P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V)	P2[4] – P2[6] – 1.675	P2[4] – P2[6] + 0.013	P2[4] – P2[6] + 1.825	V
	RefPower = medium Opamp bias = low	V _{REFHI}	Ref High	P2[4]+P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V)	P2[4] + P2[6] – 0.098	P2[4] + P2[6] – 0.011	P2[4] + P2[6] + 0.067	V
		V _{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	—
		V _{REFLO}	Ref Low	P2[4]–P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V)	P2[4] – P2[6] – 0.308	P2[4] – P2[6] + 0.004	P2[4] – P2[6] + 0.362	V
	RefPower = low Opamp bias = high	V _{REFHI}	Ref High	P2[4]+P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V)	P2[4] + P2[6] – 0.042	P2[4] + P2[6] – 0.005	P2[4] + P2[6] + 0.035	V
		V _{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	—
		V _{REFLO}	Ref Low	P2[4]–P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V)	P2[4] – P2[6] – 0.030	P2[4] – P2[6]	P2[4] – P2[6] + 0.030	V
	RefPower = low Opamp bias = low	V _{REFHI}	Ref High	P2[4]+P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V)	P2[4] + P2[6] – 0.367	P2[4] + P2[6] – 0.005	P2[4] + P2[6] + 0.308	V
		V _{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	—
		V _{REFLO}	Ref Low	P2[4]–P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V)	P2[4] – P2[6] – 0.345	P2[4] – P2[6]	P2[4] – P2[6] + 0.301	V
0b010	RefPower = high Opamp bias = high	V _{REFHI}	Ref High	V _{DD}	V _{DD} – 0.100	V _{DD} – 0.003	V _{DD}	V
		V _{AGND}	AGND	V _{DD} /2	V _{DD} /2 – 0.038	V _{DD} /2	V _{DD} /2 + 0.036	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.005	V _{SS} + 0.016	V
	RefPower = high Opamp bias = low	V _{REFHI}	Ref High	V _{DD}	V _{DD} – 0.065	V _{DD} – 0.002	V _{DD}	V
		V _{AGND}	AGND	V _{DD} /2	V _{DD} /2 – 0.025	V _{DD} /2	V _{DD} /2 + 0.023	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.003	V _{SS} + 0.012	V
	RefPower = medium Opamp bias = high	V _{REFHI}	Ref High	V _{DD}	V _{DD} – 0.054	V _{DD} – 0.002	V _{DD}	V
		V _{AGND}	AGND	V _{DD} /2	V _{DD} /2 – 0.024	V _{DD} /2 – 0.001	V _{DD} /2 + 0.020	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.002	V _{SS} + 0.012	V
	RefPower = medium Opamp bias = low	V _{REFHI}	Ref High	V _{DD}	V _{DD} – 0.042	V _{DD} – 0.002	V _{DD}	V
		V _{AGND}	AGND	V _{DD} /2	V _{DD} /2 – 0.027	V _{DD} /2 – 0.001	V _{DD} /2 + 0.022	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.001	V _{SS} + 0.010	V
	RefPower = low Opamp bias = high	V _{REFHI}	Ref High	V _{DD}	V _{DD} – 0.042	V _{DD} – 0.002	V _{DD}	V
		V _{AGND}	AGND	V _{DD} /2	V _{DD} /2 – 0.028	V _{DD} /2 – 0.001	V _{DD} /2 + 0.023	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.001	V _{SS} + 0.010	V
	RefPower = low Opamp bias = low	V _{REFHI}	Ref High	V _{DD}	V _{DD} – 0.036	V _{DD} – 0.002	V _{DD}	V
		V _{AGND}	AGND	V _{DD} /2	V _{DD} /2 – 0.184	V _{DD} /2 – 0.001	V _{DD} /2 + 0.159	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.001	V _{SS} + 0.009	V

Table 24. 2.7-V DC Analog Reference Specifications (continued) (continued)

Reference ARF_CR [5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Units
0b011	All power settings Not allowed at 2.7 V	—	—	—	—	—	—	—
0b100	All power settings Not allowed at 2.7 V	—	—	—	—	—	—	—
0b101	All power settings Not allowed at 2.7 V	—	—	—	—	—	—	—
0b110	RefPower = high Opamp bias = high	V _{REFHI}	Ref High	2 × Bandgap	Not allowed	Not allowed	Not allowed	V
		V _{AGND}	AGND	Bandgap	1.160	1.302	1.340	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.007	V _{SS} + 0.025	V
	RefPower = high Opamp bias = low	V _{REFHI}	Ref High	2 × Bandgap	Not allowed	Not allowed	Not allowed	V
		V _{AGND}	AGND	Bandgap	1.160	1.301	1.338	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.004	V _{SS} + 0.017	V
	RefPower = medium Opamp bias = high	V _{REFHI}	Ref High	2 × Bandgap	Not allowed	Not allowed	Not allowed	V
		V _{AGND}	AGND	Bandgap	1.160	1.301	1.338	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.003	V _{SS} + 0.013	V
	RefPower = medium Opamp bias = low	V _{REFHI}	Ref High	2 × Bandgap	Not allowed	Not allowed	Not allowed	V
		V _{AGND}	AGND	Bandgap	1.160	1.300	1.337	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.002	V _{SS} + 0.011	V
	RefPower = low Opamp bias = high	V _{REFHI}	Ref High	2 × Bandgap	Not allowed	Not allowed	Not allowed	V
		V _{AGND}	AGND	Bandgap	1.252	1.300	1.339	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.002	V _{SS} + 0.011	V
	RefPower = low Opamp bias = low	V _{REFHI}	Ref High	2 × Bandgap	Not allowed	Not allowed	Not allowed	V
		V _{AGND}	AGND	Bandgap	1.252	1.300	1.339	V
		V _{REFLO}	Ref Low	V _{SS}	V _{SS}	V _{SS} + 0.001	V _{SS} + 0.01	V
0b111	All power settings Not allowed at 2.7 V	—	—	—	—	—	—	—

DC Analog PSoC Block Specifications

Table 23 lists the guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 2.4 V to 3.0 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters are measured at 5 V, 3.3 V, and 2.7 V at 25 °C and are for design guidance only.

Table 25. DC Analog PSoC Block Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
R _{CT}	Resistor unit value (continuous time)	—	12.2	—	kΩ	
C _{SC}	Capacitor unit value (switched capacitor)	—	80	—	fF	

DC POR, SMP, and LVD Specifications

Table 24 lists the guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 2.4 V to 3.0 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters are measured at 5 V, 3.3 V, and 2.7 V at 25 °C and are for design guidance only.

Note The bits PORLEV and VM in the following table refer to bits in the VLT_CR register. See the [PSoC Programmable System-on-Chip Technical Reference Manual](#) for more information on the VLT_CR register.

Table 26. DC POR and LVD Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V _{PPOR0} V _{PPOR1} V _{PPOR2}	V _{DD} value for PPOR trip PORLEV[1:0] = 00b PORLEV[1:0] = 01b PORLEV[1:0] = 10b	—	2.36 2.82 4.55	2.40 2.95 4.70	V V V	V _{DD} must be greater than or equal to 2.5 V during startup, reset from the XRES pin, or reset from watchdog.
V _{LVD0} V _{LVD1} V _{LVD2} V _{LVD3} V _{LVD4} V _{LVD5} V _{LVD6} V _{LVD7}	V _{DD} value for LVD trip VM[2:0] = 000b VM[2:0] = 001b VM[2:0] = 010b VM[2:0] = 011b VM[2:0] = 100b VM[2:0] = 101b VM[2:0] = 110b VM[2:0] = 111b	2.40 2.85 2.95 3.06 4.37 4.50 4.62 4.71	2.45 2.92 3.02 3.13 4.48 4.64 4.73 4.81	2.51 ^[12] 2.99 ^[13] 3.09 3.20 4.55 4.75 4.83 4.95	V V V V V V V V	
V _{PUMP0} V _{PUMP1} V _{PUMP2} V _{PUMP3} V _{PUMP4} V _{PUMP5} V _{PUMP6} V _{PUMP7}	V _{DD} value for SMP trip VM[2:0] = 000b VM[2:0] = 001b VM[2:0] = 010b VM[2:0] = 011b VM[2:0] = 100b VM[2:0] = 101b VM[2:0] = 110b VM[2:0] = 111b	2.50 2.96 3.03 3.18 4.54 4.62 4.71 4.89	2.55 3.02 3.10 3.25 4.64 4.73 4.82 5.00	2.62 ^[14] 3.09 3.16 3.32 ^[15] 4.74 4.83 4.92 5.12	V V V V V V V V	

Notes

12. Always greater than 50 mV above V_{PPOR} (PORLEV=00) for falling supply.
13. Always greater than 50 mV above V_{PPOR} (PORLEV=01) for falling supply.
14. Always greater than 50 mV above V_{LVD0}.
15. Always greater than 50 mV above V_{LVD3}.

AC Electrical Characteristics

AC Chip-Level Specifications

These tables list the guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 2.4 V to 3.0 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters are measured at 5 V, 3.3 V, and 2.7 V at 25 °C and are for design guidance only.

Table 29. 5-V and 3.3-V AC Chip-Level Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
F _{IMO24} ^[19]	Internal main oscillator (IMO) frequency for 24 MHz	22.8	24	25.2 ^[20,21]	MHz	Trimmed for 5 V or 3.3 V operation using factory trim values. See Figure 8 on page 18 . SLIMO mode = 0.
F _{IMO6}	IMO frequency for 6 MHz	5.5	6	6.5 ^[20,21]	MHz	Trimmed for 5 V or 3.3 V operation using factory trim values. See Figure 8 on page 18 . SLIMO mode = 1.
F _{CPU1}	CPU frequency (5 V nominal)	0.937	24	24.6 ^[20]	MHz	SLIMO mode = 0.
F _{CPU2}	CPU frequency (3.3 V nominal)	0.937	12	12.3 ^[21]	MHz	SLIMO mode = 0.
F _{48M}	Digital PSoC block frequency	0	48	49.2 ^[20,22]	MHz	Refer to the AC Digital Block Specifications.
F _{24M}	Digital PSoC block frequency	0	24	24.6 ^[22]	MHz	
F _{32K1}	ILO frequency	15	32	64	kHz	
F _{32K2}	External crystal oscillator	–	32.768	–	kHz	Accuracy is capacitor and crystal dependent. 50% duty cycle.
F _{32K_U}	ILO untrimmed frequency	5	–	100	kHz	After a reset and before the M8C starts to run, the ILO is not trimmed. See the System Resets section of the PSoC Technical Reference Manual for details on timing this
F _{PLL}	PLL frequency	–	23.986	–	MHz	Is a multiple (x732) of crystal frequency.
T _{PLLSLEW}	PLL lock time	0.5	–	10	ms	
T _{PLLSLEWSLOW}	PLL lock time for low gain setting	0.5	–	50	ms	
T _{OS}	External crystal oscillator startup to 1%	–	1700	2620	ms	
T _{OSACC}	External crystal oscillator startup to 100 ppm	–	2800	3800	ms	The crystal oscillator frequency is within 100 ppm of its final value by the end of the T _{OSACC} period. Correct operation assumes a properly loaded 1 μW maximum drive level 32.768 kHz crystal. 3.0 V ≤ V _{DD} ≤ 5.5 V, –40 °C ≤ T _A ≤ 85 °C.
t _{XRST}	External reset pulse width	10	–	–	μs	

Notes

19. Errata: When the device is operated within 0 °C to 70 °C, the frequency tolerance is reduced to ±2.5%, but if operated at extreme temperature (below 0 °C or above 70 °C), frequency tolerance deviates from ±2.5% to ±5%. For more information, see “Errata” on page 67.

20. 4.75 V < V_{DD} < 5.25 V.

21. 3.0 V < V_{DD} < 3.6 V. See application note [Adjusting PSoC® Trims for 3.3 V and 2.7 V Operation – AN2012](#) for information on trimming for operation at 3.3 V.

22. See the individual user module datasheets for information on maximum frequencies for user modules.

23. Refer to Cypress Jitter Specifications application note, [Understanding Datasheet Jitter Specifications for Cypress Timing Products – AN5054](#) for more information.

Table 29. 5-V and 3.3-V AC Chip-Level Specifications (continued)

Symbol	Description	Min	Typ	Max	Units	Notes
DC24M	24 MHz duty cycle	40	50	60	%	
DC _{ILO}	ILO duty cycle	20	50	80	%	
Step24M	24 MHz trim step size	–	50	–	kHz	
F _{out48M}	48 MHz output frequency	46.8	48.0	49.2 ^[24, 25]	MHz	Trimmed. Using factory trim values.
F _{MAX}	Maximum frequency of signal on row input or row output.	–	–	12.3	MHz	
SR _{POWER_UP}	Power supply slew rate	–	–	250	V/ms	V _{DD} slew rate during power-up.
t _{POWERUP}	Time from end of POR to CPU executing code	–	16	100	ms	Power-up from 0 V. See the System Resets section of the PSoC Technical Reference Manual .
t _{jitter_IMO} ^[26]	24 MHz IMO cycle-to-cycle jitter (RMS)	–	200	700	ps	N = 32
	24 MHz IMO long term N cycle-to-cycle jitter (RMS)	–	300	900	ps	
	24 MHz IMO period jitter (RMS)	–	100	400	ps	
t _{jitter_PLL} ^[26]	24 MHz IMO cycle-to-cycle jitter (RMS)	–	200	800	ps	N = 32
	24 MHz IMO long term N cycle-to-cycle jitter (RMS)	–	300	1200		
	24 MHz IMO period jitter (RMS)	–	100	700		

Notes

 24. 4.75 V < V_{DD} < 5.25 V.

 25. 3.0 V < V_{DD} < 3.6 V. See application note [Adjusting PSoC® Trims for 3.3 V and 2.7 V Operation – AN2012](#) for information on trimming for operation at 3.3 V.

 26. Refer to Cypress Jitter Specifications application note, [Understanding Datasheet Jitter Specifications for Cypress Timing Products – AN5054](#) for more information.

AC Digital Block Specifications

The following tables list the guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 2.4 V to 3.0 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters are measured at 5 V, 3.3 V, and 2.7 V at 25°C and are for design guidance only.

Table 37. 5-V and 3.3-V AC Digital Block Specifications

Function	Description	Min	Typ	Max	Unit	Notes
All functions	Block input clock frequency					
	$V_{DD} \geq 4.75\text{ V}$	–	–	50.4	MHz	
	$V_{DD} < 4.75\text{ V}$	–	–	25.2	MHz	
Timer	Input clock frequency					
	No capture, $V_{DD} \geq 4.75\text{ V}$	–	–	50.4	MHz	
	No capture, $V_{DD} < 4.75\text{ V}$	–	–	25.2	MHz	
	With capture	–	–	25.2	MHz	
	Capture pulse width	50 ^[30]	–	–	ns	
Counter	Input clock frequency					
	No enable input, $V_{DD} \geq 4.75\text{ V}$	–	–	50.4	MHz	
	No enable input, $V_{DD} < 4.75\text{ V}$	–	–	25.2	MHz	
	With enable input	–	–	25.2	MHz	
	Enable input pulse width	50 ^[30]	–	–	ns	
Dead Band	Kill pulse width					
	Asynchronous restart mode	20	–	–	ns	
	Synchronous restart mode	50 ^[30]	–	–	ns	
	Disable mode	50 ^[30]	–	–	ns	
	Input clock frequency					
	$V_{DD} \geq 4.75\text{ V}$	–	–	50.4	MHz	
	$V_{DD} < 4.75\text{ V}$	–	–	25.2	MHz	
CRCPRS (PRS Mode)	Input clock frequency					
	$V_{DD} \geq 4.75\text{ V}$	–	–	50.4	MHz	
	$V_{DD} < 4.75\text{ V}$	–	–	25.2	MHz	
CRCPRS (CRC Mode)	Input clock frequency	–	–	25.2	MHz	
SPIM	Input clock frequency	–	–	8.2	MHz	The SPI serial clock (SCLK) frequency is equal to the input clock frequency divided by 2.
SPIS	Input clock (SCLK) frequency	–	–	4.1	MHz	The input clock is the SPI SCLK in SPIS mode.
	Width of SS _{negated} between transmissions	50 ^[30]	–	–	ns	
Transmitter	Input clock frequency					The baud rate is equal to the input clock frequency divided by 8.
	$V_{DD} \geq 4.75\text{ V}$, 2 stop bits	–	–	50.4	MHz	
	$V_{DD} \geq 4.75\text{ V}$, 1 stop bit	–	–	25.2	MHz	
	$V_{DD} < 4.75\text{ V}$	–	–	25.2	MHz	
Receiver	Input clock frequency					The baud rate is equal to the input clock frequency divided by 8.
	$V_{DD} \geq 4.75\text{ V}$, 2 stop bits	–	–	50.4	MHz	
	$V_{DD} \geq 4.75\text{ V}$, 1 stop bit	–	–	25.2	MHz	
	$V_{DD} < 4.75\text{ V}$	–	–	25.2	MHz	

Note

30. 50 ns minimum input pulse width is based on the input synchronizers running at 24 MHz (42 ns nominal period).

Table 38. 2.7-V AC Digital Block Specifications

Function	Description	Min	Typ	Max	Units	Notes
All Functions	Block input clock frequency	–	–	12.7	MHz	2.4 V < V _{DD} < 3.0 V
Timer	Capture pulse width	100 ^[31]	–	–	ns	
	Input clock frequency, with or without capture	–	–	12.7	MHz	
Counter	Enable Input Pulse Width	100 ^[31]	–	–	ns	
	Input clock frequency, no enable input	–	–	12.7	MHz	
	Input clock frequency, enable input	–	–	12.7	MHz	
Dead Band	Kill pulse width:					
	Asynchronous restart mode	20	–	–	ns	
	Synchronous restart mode	100 ^[31]	–	–	ns	
	Disable mode	100 ^[31]	–	–	ns	
	Input clock frequency	–	–	12.7	MHz	
CRCPRS (PRS Mode)	Input clock frequency	–	–	12.7	MHz	
CRCPRS (CRC Mode)	Input clock frequency	–	–	12.7	MHz	
SPIM	Input clock frequency	–	–	6.35	MHz	The SPI serial clock (SCLK) frequency is equal to the input clock frequency divided by 2.
SPIS	Input clock frequency	–	–	4.23	MHz	
	Width of SS_ Negated between transmissions	100 ^[31]	–	–	ns	
Transmitter	Input clock frequency	–	–	12.7	MHz	The baud rate is equal to the input clock frequency divided by 8.
Receiver	Input clock frequency	–	–	12.7	MHz	The baud rate is equal to the input clock frequency divided by 8.

Note

31. 50 ns minimum input pulse width is based on the input synchronizers running at 12 MHz (84 ns nominal period).

Table 41. 2.7-V AC Analog Output Buffer Specifications

Symbol	Description	Min	Typ	Max	Units
t_{ROB}	Rising settling time to 0.1%, 1 V Step, 100 pF load Power = low Power = high	–	–	4	μs
		–	–	4	μs
t_{SOB}	Falling settling time to 0.1%, 1 V Step, 100 pF load Power = low Power = high	–	–	3	μs
		–	–	3	μs
SR_{ROB}	Rising slew rate (20% to 80%), 1 V Step, 100 pF load Power = low Power = high	0.4	–	–	V/ μs
		0.4	–	–	V/ μs
SR_{FOB}	Falling slew rate (80% to 20%), 1 V Step, 100 pF load Power = low Power = high	0.4	–	–	V/ μs
		0.4	–	–	V/ μs
BW_{OB}	Small signal bandwidth, 20 mV _{pp} , 3dB BW, 100 pF load Power = low Power = high	0.6	–	–	MHz
		0.6	–	–	MHz
BW_{OB}	Large signal bandwidth, 1 V _{pp} , 3dB BW, 100 pF load Power = low Power = high	180	–	–	kHz
		180	–	–	kHz

AC External Clock Specifications

The following tables list the guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 2.4 V to 3.0 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters are measured at 5 V, 3.3 V, and 2.7 V at 25 °C and are for design guidance only.

Table 42. 5-V AC External Clock Specifications

Symbol	Description	Min	Typ	Max	Units
F_{OSCEXT}	Frequency	0.093	–	24.6	MHz
–	High period	20.6	–	5300	ns
–	Low period	20.6	–	–	ns
–	Power-up IMO to switch	150	–	–	μs

Table 43. 3.3-V AC External Clock Specifications

Symbol	Description	Min	Typ	Max	Units
F_{OSCEXT}	Frequency with CPU clock divide by 1 ^[32]	0.093	–	12.3	MHz
F_{OSCEXT}	Frequency with CPU clock divide by 2 or greater ^[33]	0.186	–	24.6	MHz
–	High period with CPU clock divide by 1	41.7	–	5300	ns
–	Low period with CPU clock divide by 1	41.7	–	–	ns
–	Power-up IMO to switch	150	–	–	μs

Notes

32. Maximum CPU frequency is 12 MHz at 3.3 V. With the CPU clock divider set to 1, the external clock must adhere to the maximum frequency and duty cycle requirements.

33. If the frequency of the external clock is greater than 12 MHz, the CPU clock divider must be set to 2 or greater. In this case, the CPU clock divider ensures that the fifty percent duty cycle requirement is met

AC I²C Specifications

The following tables list the guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 2.4 V to 3.0 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters are measured at 5 V, 3.3 V, and 2.7 V at 25°C and are for design guidance only.

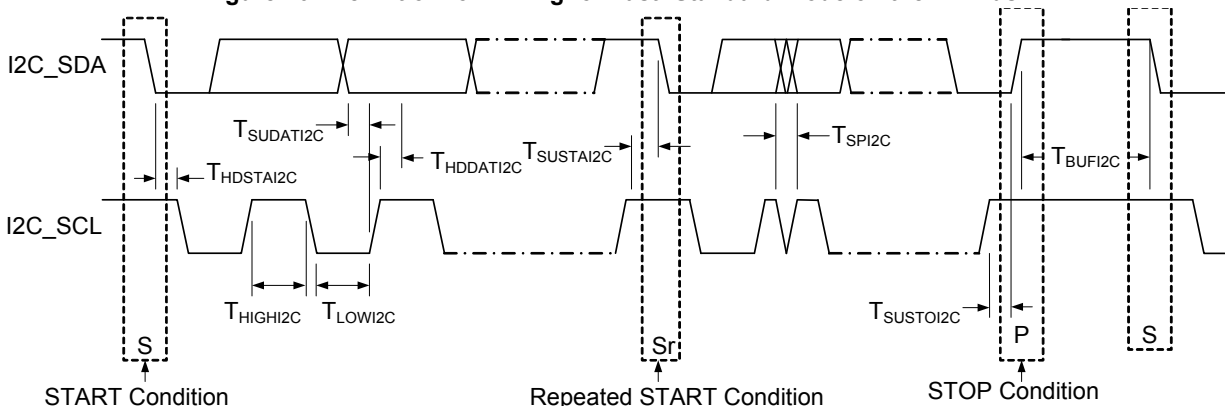
Table 46. AC Characteristics of the I²C SDA and SCL Pins for $V_{DD} > 3.0\text{ V}$

Symbol	Description	Standard-Mode		Fast-Mode		Units
		Min	Max	Min	Max	
$F_{SCL I2C}$	SCL clock frequency	0	100	0	400	kHz
$t_{HDSTA I2C}$	Hold time (repeated) start condition. After this period, the first clock pulse is generated	4.0	—	0.6	—	μs
$t_{LOW I2C}$	Low period of the SCL clock	4.7	—	1.3	—	μs
$t_{HIGH I2C}$	High period of the SCL clock	4.0	—	0.6	—	μs
$t_{SUSTA I2C}$	Setup time for a repeated start condition	4.7	—	0.6	—	μs
$t_{HDDAT I2C}$	Data hold time	0	—	0	—	μs
$t_{SUDAT I2C}$	Data setup time	250	—	100 ^[37]	—	ns
$t_{SUSTOI2C}$	Setup time for stop condition	4.0	—	0.6	—	μs
t_{BUFI2C}	Bus free time between a stop and start condition	4.7	—	1.3	—	μs
t_{SPI2C}	Pulse width of spikes are suppressed by the input filter	—	—	0	50	ns

Table 47. AC Characteristics of the I²C SDA and SCL Pins for $V_{DD} < 3.0\text{ V}$ (Fast Mode Not Supported)

Symbol	Description	Standard-Mode		Fast-Mode		Units
		Min	Max	Min	Max	
$F_{SCL I2C}$	SCL clock frequency	0	100	—	—	kHz
$t_{HDSTA I2C}$	Hold time (repeated) start condition. After this period, the first clock pulse is generated	4.0	—	—	—	μs
$t_{LOW I2C}$	Low period of the SCL clock	4.7	—	—	—	μs
$t_{HIGH I2C}$	High period of the SCL clock	4.0	—	—	—	μs
$t_{SUSTA I2C}$	Setup time for a repeated start condition	4.7	—	—	—	μs
$t_{HDDAT I2C}$	Data hold time	0	—	—	—	μs
$t_{SUDAT I2C}$	Data setup time	250	—	—	—	ns
$t_{SUSTOI2C}$	Setup time for stop condition	4.0	—	—	—	μs
t_{BUFI2C}	Bus free time between a stop and start condition	4.7	—	—	—	μs
t_{SPI2C}	Pulse width of spikes are suppressed by the input filter	—	—	—	—	ns

Figure 16. Definition for Timing for Fast-/Standard-Mode on the I²C Bus



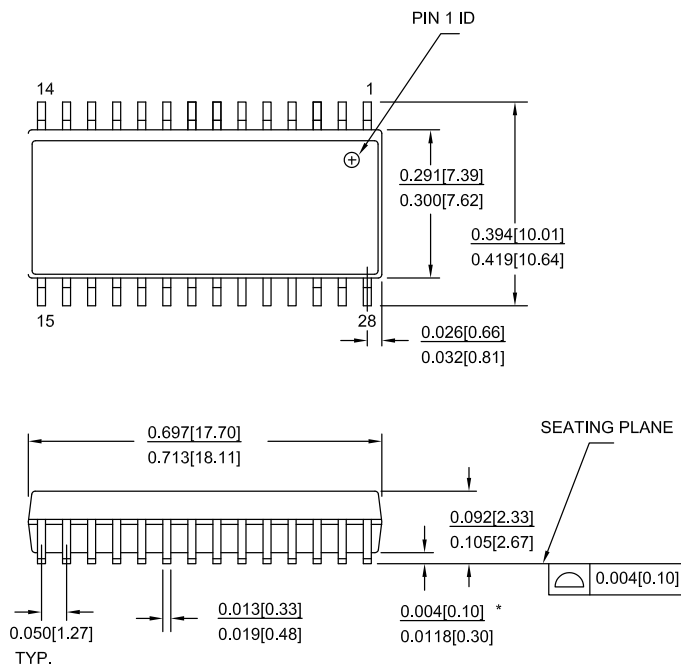
Note

37. A fast-mode I²C-bus device can be used in a Standard-Mode I²C-bus system, but the requirement $t_{SUDAT} \geq 250\text{ ns}$ must then be met. This is automatically the case if the device does not stretch the LOW period of the SCL signal. If such device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line $t_{max} + t_{SUDAT} = 1000 + 250 = 1250\text{ ns}$ (according to the Standard-Mode I²C-bus specification) before the SCL line is released.

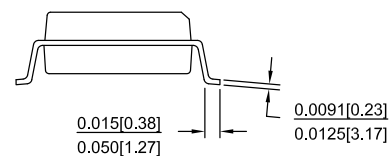
Figure 24. 28-Pin (300-Mil) Molded SOIC

NOTE :

1. JEDEC STD REF MO-119
2. BODY LENGTH DIMENSION DOES NOT INCLUDE MOLD PROTRUSION/END FLASH, BUT DOES INCLUDE MOLD MISMATCH AND ARE MEASURED AT THE MOLD PARTING LINE. MOLD PROTRUSION/END FLASH SHALL NOT EXCEED 0.010 in (0.254 mm) PER SIDE
3. DIMENSIONS IN INCHES MIN.
MAX.



PART #	
S28.3	STANDARD PKG.
SZ28.3	LEAD FREE PKG.
SX28.3	LEAD FREE PKG.



51-85026 *H

Acronyms

Acronyms Used

Table 53 lists the acronyms that are used in this document.

Table 53. Acronyms Used in this Datasheet

Acronym	Description	Acronym	Description
AC	alternating current	MIPS	million instructions per second
ADC	analog-to-digital converter	OCD	on-chip debug
API	application programming interface	PCB	printed circuit board
CMOS	complementary metal oxide semiconductor	PDIP	plastic dual-in-line package
CPU	central processing unit	PGA	programmable gain amplifier
CRC	cyclic redundancy check	PLL	phase-locked loop
CT	continuous time	POR	power on reset
DAC	digital-to-analog converter	PPOR	precision power on reset
DC	direct current	PRS	pseudo-random sequence
DTMF	dual-tone multi-frequency	PSoC®	Programmable System-on-Chip
ECO	external crystal oscillator	PWM	pulse width modulator
EEPROM	electrically erasable programmable read-only memory	QFN	quad flat no leads
GPIO	general purpose I/O	RTC	real time clock
ICE	in-circuit emulator	SAR	successive approximation
IDE	integrated development environment	SC	switched capacitor
ILO	internal low speed oscillator	SLIMO	slow IMO
IMO	internal main oscillator	SMP	switch mode pump
I/O	input/output	SOIC	small-outline integrated circuit
IrDA	infrared data association	SPI™	serial peripheral interface
ISSP	in-system serial programming	SRAM	static random access memory
LCD	liquid crystal display	SROM	supervisory read only memory
LED	light-emitting diode	SSOP	shrink small-outline package
LPC	low power comparator	UART	universal asynchronous receiver / transmitter
LVD	low voltage detect	USB	universal serial bus
MAC	multiply-accumulate	WDT	watchdog timer
MCU	microcontroller unit	XRES	external reset

Reference Documents

CY8CPLC20, CY8CLED16P01, CY8C29x66, CY8C27x43, CY8C24x94, CY8C24x23, CY8C24x23A, CY8C22x13, CY8C21x34, CY8C21x23, CY7C64215, CY7C603xx, CY8CNP1xx, and CYWUSB6953 PSoC® Programmable System-on-Chip Technical Reference Manual (TRM) (001-14463)

Design Aids – Reading and Writing PSoC® Flash – AN2015 (001-40459)

Application Notes for Surface Mount Assembly of Amkor's MicroLeadFrame (MLF) Packages – available at <http://www.amkor.com>.

Glossary (continued)

microcontroller	An integrated circuit chip that is designed primarily for control systems and products. In addition to a CPU, a microcontroller typically includes memory, timing circuits, and IO circuitry. The reason for this is to permit the realization of a controller with a minimal quantity of chips, thus achieving maximal possible miniaturization. This in turn, reduces the volume and the cost of the controller. The microcontroller is normally not used for general-purpose computation as is a microprocessor.
mixed-signal	The reference to a circuit containing both analog and digital techniques and components.
modulator	A device that imposes a signal on a carrier.
noise	<ol style="list-style-type: none"> 1. A disturbance that affects a signal and that may distort the information carried by the signal. 2. The random variations of one or more characteristics of any entity such as voltage, current, or data.
oscillator	A circuit that may be crystal controlled and is used to generate a clock frequency.
parity	A technique for testing transmitting data. Typically, a binary digit is added to the data to make the sum of all the digits of the binary data either always even (even parity) or always odd (odd parity).
phase-locked loop (PLL)	An electronic circuit that controls an oscillator so that it maintains a constant phase angle relative to a reference signal.
pinouts	The pin number assignment: the relation between the logical inputs and outputs of the PSoC device and their physical counterparts in the printed circuit board (PCB) package. Pinouts involve pin numbers as a link between schematic and PCB design (both being computer generated files) and may also involve pin names.
port	A group of pins, usually eight.
power on reset (POR)	A circuit that forces the PSoC device to reset when the voltage is lower than a pre-set level. This is one type of hardware reset.
PSoC®	Cypress Semiconductor's PSoC® is a registered trademark and Programmable System-on-Chip™ is a trademark of Cypress.
PSoC Designer™	The software for Cypress' Programmable System-on-Chip technology.
pulse width modulator (PWM)	An output in the form of duty cycle which varies as a function of the applied measurand
RAM	An acronym for random access memory. A data-storage device from which data can be read out and new data can be written in.
register	A storage device with a specific capacity, such as a bit or byte.
reset	A means of bringing a system back to a know state. See hardware reset and software reset.
ROM	An acronym for read only memory. A data-storage device from which data can be read out, but new data cannot be written in.
serial	<ol style="list-style-type: none"> 1. Pertaining to a process in which all events occur one after the other. 2. Pertaining to the sequential or consecutive occurrence of two or more related activities in a single device or channel.
settling time	The time it takes for an output signal or value to stabilize after the input has changed from one value to another.